

GaAs IC SPDT Reflective Switch Positive Control DC–2 GHz



AS170-92

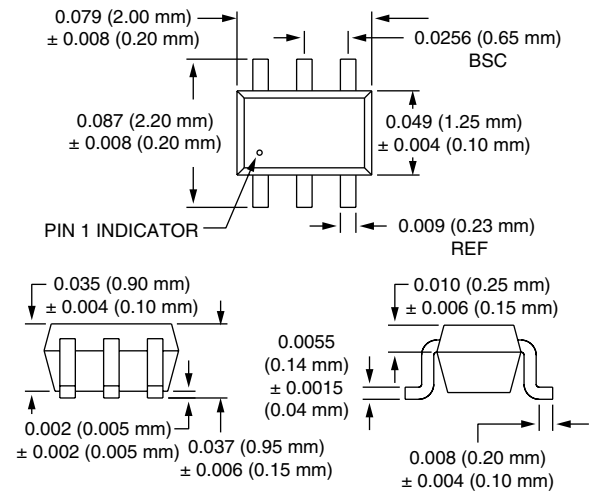
Features

- Low Insertion Loss
- Positive Control Voltage
- Low DC Power Consumption
- Ultra Miniature SC-70 6 Lead Package

Description

The AS170-92 is an IC FET reflective SPDT switch in a low cost miniature SC-70 6 lead plastic package. The AS170-92 features low insertion loss and positive voltage operation with very low DC power consumption. This general purpose switch provides a low cost solution for IF switching requirements in dual band and dual mode applications.

SC-70 6 Lead



Electrical Specifications at 25°C (0, +3 V)

Parameter ¹	Frequency ²	Min.	Typ.	Max.	Unit
Insertion Loss ³	DC–1.0 GHz		0.45	0.6	dB
	DC–2.0 GHz		0.60	0.8	dB
Isolation	DC–1.0 GHz	15	18		dB
	DC–2.0 GHz	10	13		dB
VSWR ⁴	DC–1.0 GHz		1.2:1		
	DC–2.0 GHz		1.5:1		

Operating Characteristics at 25°C (0, +3 V)

Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics ⁵	Rise, Fall (10/90% or 90/10% RF)			10		ns
	On, Off (50% CTL to 90/10% RF)			20		ns
	Video Feedthru			25		mV
Input Power for 1 dB Compression	0/+3 V	0.5–2.0 GHz		+21		dBm
	0/+5 V	0.5–2.0 GHz		+28		dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power +13 dBm					
	0/+3 V	0.5–2.0 GHz		+36		dBm
	0/+5 V	0.5–2.0 GHz		+45		dBm
Control Voltages	$V_{Low} = 0 \text{ to } 0.2 \text{ V @ } 20 \mu\text{A Max.}$					
	$V_{High} = +3 \text{ V @ } 100 \mu\text{A Max. to } +5 \text{ V @ } 200 \mu\text{A Max.}$					

1. All measurements made in a 50 Ω system, unless otherwise specified.

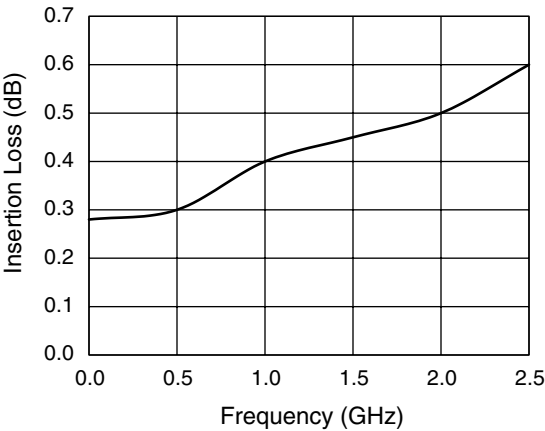
2. DC = 300 kHz.

3. Insertion loss changes by 0.003 dB/°C.

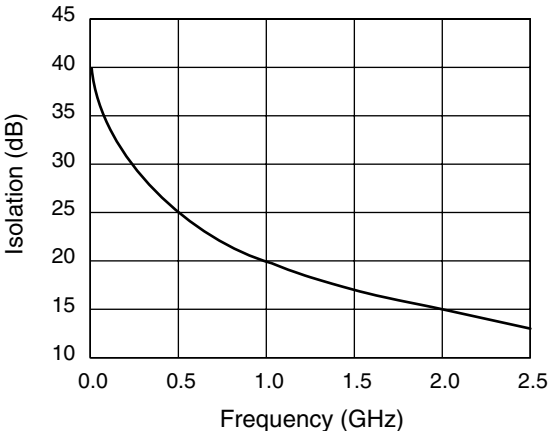
4. Insertion loss state.

5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

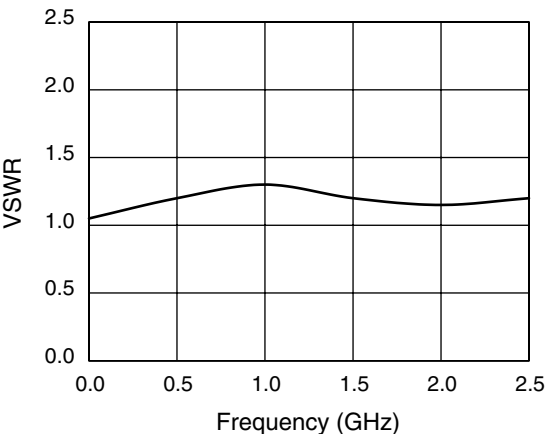
Typical Performance Data (0, +3 V)



Insertion Loss vs. Frequency



Isolation vs. Frequency



VSWR vs. Frequency

Truth Table

V ₁	V ₂	J ₁ –J ₂	J ₁ –J ₃
V _{High}	0	Insertion Loss	Isolation
0	V _{High}	Isolation	Insertion Loss

V_{High} = +3 to +5 V.

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	2 W > 500 MHz 0/+7 V Control
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-50°C to +150°C
Θ _{JC}	25°C/W

Pin Out

